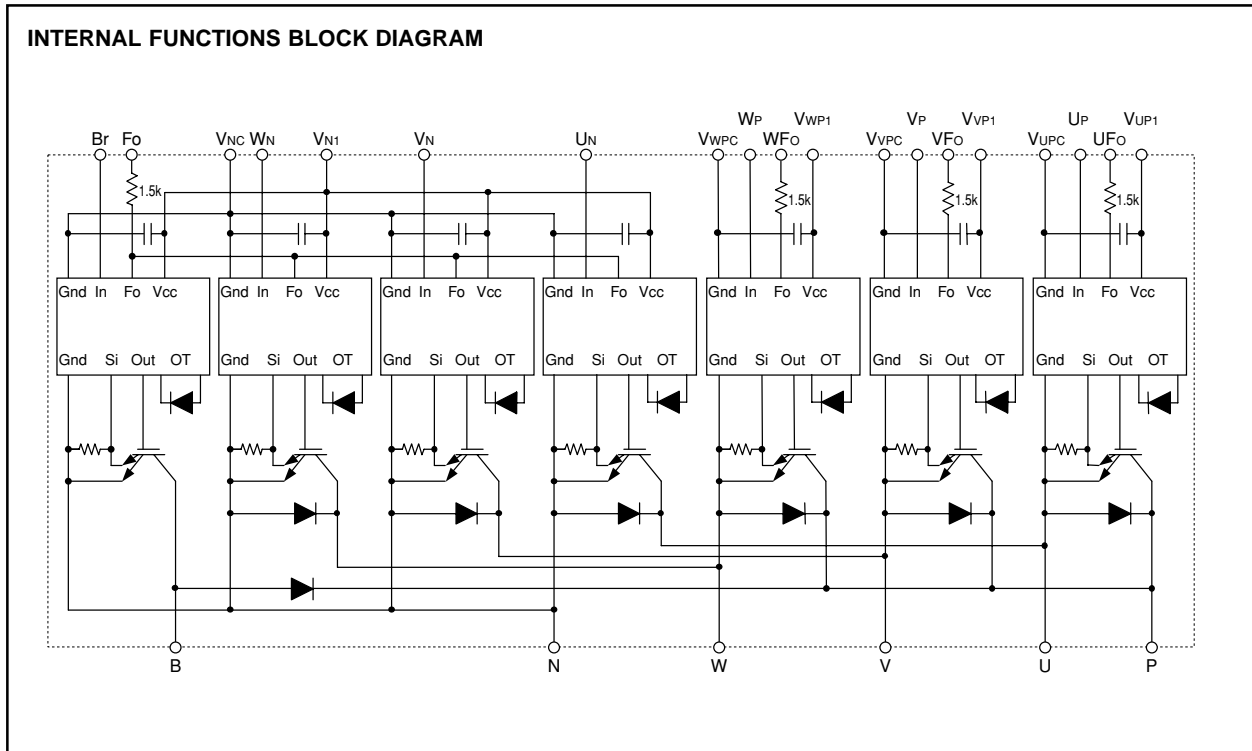


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FLAT-BASE TYPE
INSULATED PACKAGE



MAXIMUM RATINGS (Tj = 25°C, unless otherwise noted)

INVERTER PART

Symbol	Parameter	Condition	Ratings	Unit
VCES	Collector-Emitter Voltage	VD = 15V, V _{CIN} = 15V	1200	V
±IC	Collector Current	Tc = 25°C	150	A
±ICP	Collector Current (Peak)	Tc = 25°C	300	A
PC	Collector Dissipation	Tc = 25°C (Note-1)	1041	W
Tj	Junction Temperature		-20 ~ +150	°C

BRAKE PART

Symbol	Parameter	Condition	Ratings	Unit
VCES	Collector-Emitter Voltage	VD = 15V, V _{CIN} = 15V	1200	V
IC	Collector Current	Tc = 25°C	75	A
ICP	Collector Current (Peak)	Tc = 25°C	150	A
PC	Collector Dissipation	Tc = 25°C (Note-1)	595	W
VR(DC)	FWDi Rated DC Reverse Voltage	Tc = 25°C	1200	V
IF	FWDi Forward Current	Tc = 25°C	75	A
Tj	Junction Temperature		-20 ~ +150	°C

CONTROL PART

Symbol	Parameter	Condition	Ratings	Unit
VD	Supply Voltage	Applied between : VUP1-VUPC VVP1-VVPC, VWP1-VWPC, VN1-VNC	20	V
V _{CIN}	Input Voltage	Applied between : UP-VUPC, VP-VVPC WP-VWPC, UN • VN • WN • Br-VNC	20	V
VFO	Fault Output Supply Voltage	Applied between : UFO-VUPC, VFO-VVPC, WFO-VWPC FO-VNC	20	V
IFO	Fault Output Current	Sink current at UFO, VFO, WFO, FO terminals	20	mA

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FLAT-BASE TYPE
INSULATED PACKAGE

TOTAL SYSTEM

Symbol	Parameter	Condition	Ratings	Unit
VCC(PROT)	Supply Voltage Protected by SC	V _D = 13.5 ~ 16.5V, Inverter Part, T _j = +125°C Start	800	V
VCC(surge)	Supply Voltage (Surge)	Applied between : P-N, Surge value	1000	V
T _{stg}	Storage Temperature		-40 ~ +125	°C
Viso	Isolation Voltage	60Hz, Sinusoidal, Charged part to Base, AC 1 min.	2500	V _{rms}

THERMAL RESISTANCES

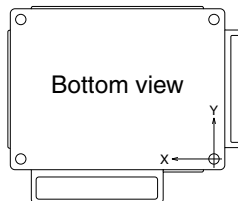
Symbol	Parameter	Condition	Limits			Unit
			Min.	Typ.	Max.	
R _{th(j-c)Q}	Junction to case Thermal Resistances	Inverter IGBT (per 1 element) (Note-1)	—	—	0.12*	°C/W
R _{th(j-c)F}		Inverter FWDi (per 1 element) (Note-1)	—	—	0.20*	
R _{th(j-c)Q}		Brake IGBT (Note-1)	—	—	0.21*	
R _{th(j-c)F}		Brake FWDi (Note-1)	—	—	0.31*	
R _{th(c-f)}	Contact Thermal Resistance	Case to fin, (per 1 module) Thermal grease applied (Note-1)	—	—	0.023	

* If you use this value, R_{th(f-a)} should be measured just under the chips.

(Note-1) T_c (under the chip) measurement point is below.

Unit : mm

axis \ arm	UP		VP		WP		UN		VN		WN		Br	
	IGBT	FWDi	IGBT	FWDi	IGBT	FWDi	IGBT	FWDi	IGBT	FWDi	IGBT	FWDi	IGBT	FWDi
X	23.0	23.0	57.5	56.5	87.5	86.5	37.0	38.0	70.5	71.5	100.5	101.5	11.0	8.0
Y	56.3	43.1	56.3	43.1	56.3	43.1	29.1	42.4	29.1	42.4	29.1	42.4	26.8	61.0



ELECTRICAL CHARACTERISTICS (T_j = 25°C, unless otherwise noted)

INVERTER PART

Symbol	Parameter	Condition	Limits			Unit	
			Min.	Typ.	Max.		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	V _D = 15V, I _c = 150A V _{CIN} = 0V (Fig. 1)	T _j = 25°C	—	1.8	2.3	V
			T _j = 125°C	—	1.9	2.4	
V _{EC}	FWDi Forward Voltage	-I _c = 150A, V _D = 15V, V _{CIN} = 15V (Fig. 2)	—	2.5	3.5	V	
t _{on}	Switching Time	V _D = 15V, V _{CIN} = 0V↔15V V _{CC} = 600V, I _c = 150A T _j = 125°C Inductive Load (Fig. 3, 4)	—	0.5	1.0	2.5	μs
t _{tr}			—	—	0.5	0.8	
t _{c(on)}			—	—	0.4	1.0	
t _{off}			—	—	2.0	3.0	
t _{c(off)}			—	—	0.7	1.2	
I _{CES}	Collector-Emitter Cutoff Current	V _{CE} = V _{CES} , V _{CIN} = 15V (Fig. 5)	T _j = 25°C	—	—	1	mA
			T _j = 125°C	—	—	10	

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BRAKE PART

Symbol	Parameter	Condition	Limits			Unit	
			Min.	Typ.	Max.		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	V _D = 15V, I _C = 75A V _{CIN} = 0V (Fig. 1)	T _J = 25°C	—	1.8	2.3	V
			T _J = 125°C	—	1.9	2.4	
V _{FM}	FWDi Forward Voltage	I _F = 75A (Fig. 2)	—	2.5	3.5	V	
I _{CES}	Collector-Emitter Cutoff Current	V _{CE} = V _{CES} , V _{CIN} = 15V (Fig. 5)	T _J = 25°C	—	—	1	mA
			T _J = 125°C	—	—	10	

CONTROL PART

Symbol	Parameter	Condition	Limits			Unit	
			Min.	Typ.	Max.		
I _D	Circuit Current	V _D = 15V, V _{CIN} = 15V	V _{N1} -V _{NC}	—	24	34	mA
			V _{P1} -V _{PC}	—	6	12	
V _{th(ON)}	Input ON Threshold Voltage	Applied between : UP-VUPC, VP-VVPC, WP-VWPC UN • VN • WN • Br-VNC	1.2	1.5	1.8	V	
V _{th(OFF)}	Input OFF Threshold Voltage		1.7	2.0	2.3		
SC	Short Circuit Trip Level	-20 ≤ T _J ≤ 125°C, V _D = 15V (Fig. 3,6)	Inverter part	300	—	—	A
			Brake part	150	—	—	
t _{off(SC)}	Short Circuit Current Delay Time	V _D = 15V (Fig. 3,6)	—	0.2	—	μs	
OT	Over Temperature Protection	V _D = 15V Detect T _J of IGBT chip	Trip level	135	145	—	°C
			Reset level	—	125	—	
UV	Supply Circuit Under-Voltage Protection	-20 ≤ T _J ≤ 125°C	Trip level	11.5	12.0	12.5	V
			Reset level	—	12.5	—	
I _{FO(H)}	Fault Output Current	V _D = 15V, V _{FO} = 15V (Note-2)	—	—	0.01	mA	
I _{FO(L)}			—	10	15		
t _{FO}	Minimum Fault Output Pulse Width	V _D = 15V (Note-2)	1.0	1.8	—	ms	

(Note-2) Fault output is given only when the internal SC, OT & UV protections schemes of either upper or lower arm device operate to protect it.

MECHANICAL RATINGS AND CHARACTERISTICS

Symbol	Parameter	Condition	Limits			Unit
			Min.	Typ.	Max.	
—	Mounting torque	Main terminal screw : M5	2.5	3.0	3.5	N • m
—	Mounting torque	Mounting part screw : M5	2.5	3.0	3.5	N • m
—	Weight	—	—	800	—	g

RECOMMENDED CONDITIONS FOR USE

Symbol	Parameter	Condition	Recommended value	Unit
V _{CC}	Supply Voltage	Applied across P-N terminals	≤ 800	V
V _D	Control Supply Voltage	Applied between : VUP1-VUPC, VVP1-VVPC VWP1-VWPC, VN1-VNC (Note-3)	15 ± 1.5	V
V _{CIN(ON)}	Input ON Voltage	Applied between : UP-VUPC, VP-VVPC, WP-VWPC UN • VN • WN • Br-VNC	≤ 0.8	V
V _{CIN(OFF)}	Input OFF Voltage		≥ 9.0	
f _{PWM}	PWM Input Frequency	Using Application Circuit of Fig. 8	≤ 20	kHz
t _{dead}	Arm Shoot-through Blocking Time	For IPM's each input signals (Fig. 7)	≥ 2.5	μs

(Note-3) With ripple satisfying the following conditions: dv/dt swing ≤ ±5V/μs, Variation ≤ 2V peak to peak

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FLAT-BASE TYPE
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PRECAUTIONS FOR TESTING

- Before applying any control supply voltage (V_D), the input terminals should be pulled up by resistors, etc. to their corresponding supply voltage and each input signal should be kept off state.
After this, the specified ON and OFF level setting for each input signal should be done.
- When performing "SC" tests, the turn-off surge voltage spike at the corresponding protection operation should not be allowed to rise above V_{CES} rating of the device.
(These test should not be done by using a curve tracer or its equivalent.)

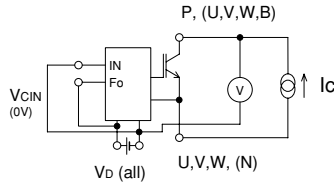


Fig. 1 $V_{CE(sat)}$ Test

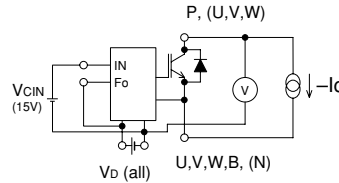
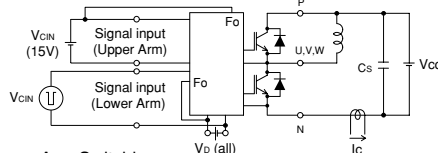


Fig. 2 V_{EC} , (V_{FM}) Test

a) Lower Arm Switching



b) Upper Arm Switching

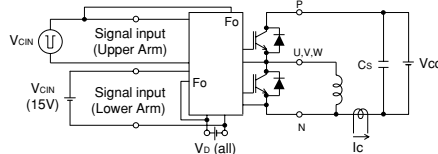


Fig. 3 Switching time and SC test circuit

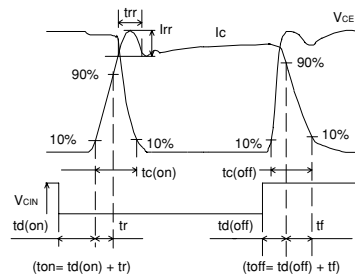


Fig. 4 Switching time test waveform

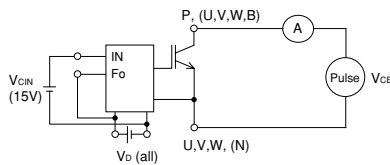


Fig. 5 I_{CES} Test

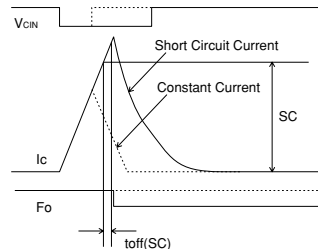
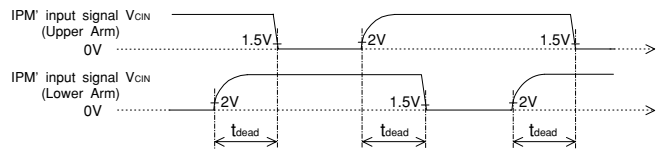


Fig. 6 SC test waveform



1.5V: Input on threshold voltage $V_{th(on)}$ typical value, 2V: Input off threshold voltage $V_{th(off)}$ typical value

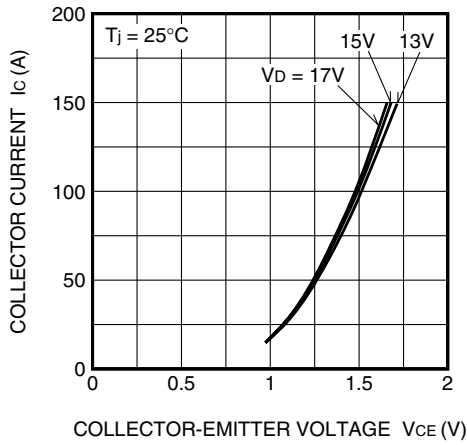
Fig. 7 Dead time measurement point example

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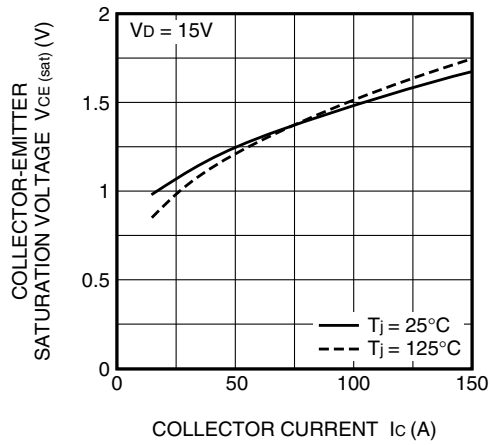
FLAT-BASE TYPE
INSULATED PACKAGE

PERFORMANCE CURVES

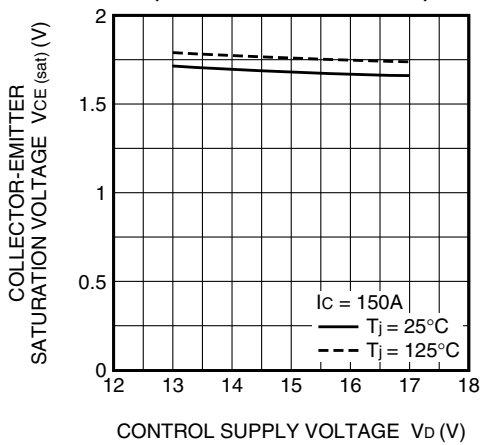
**OUTPUT CHARACTERISTICS
(INVERTER PART · TYPICAL)**



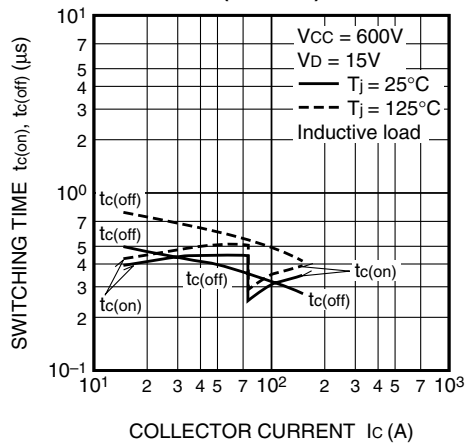
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VOLTAGE (VS. I_c) CHARACTERISTICS
(INVERTER PART · TYPICAL)**



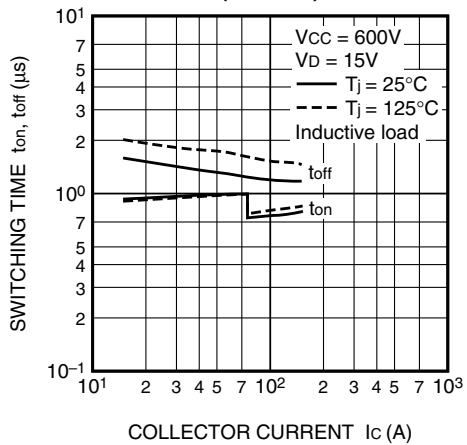
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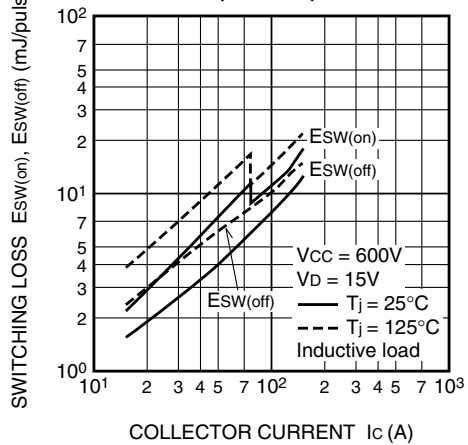
**SWITCHING TIME CHARACTERISTICS
(TYPICAL)**



**SWITCHING TIME CHARACTERISTICS
(TYPICAL)**

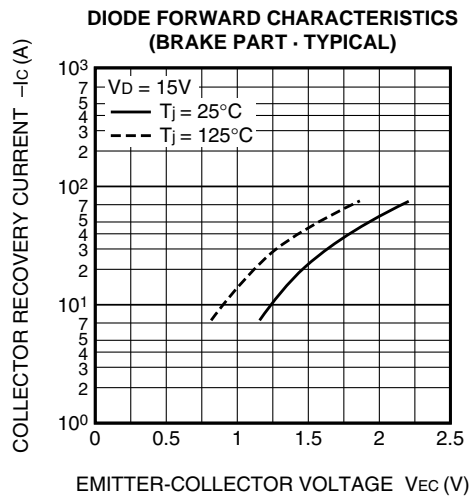
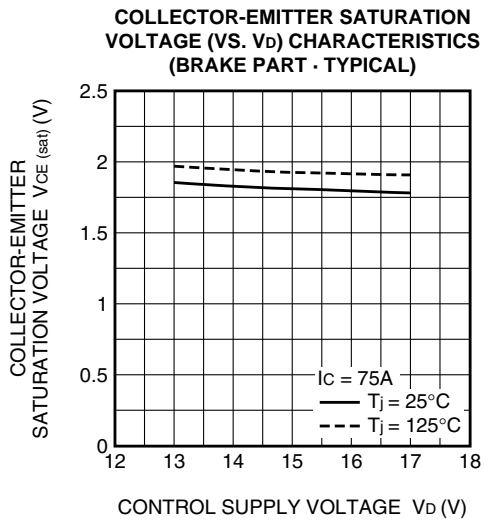
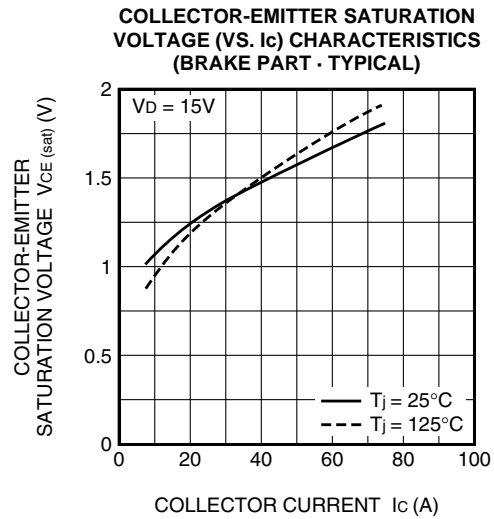
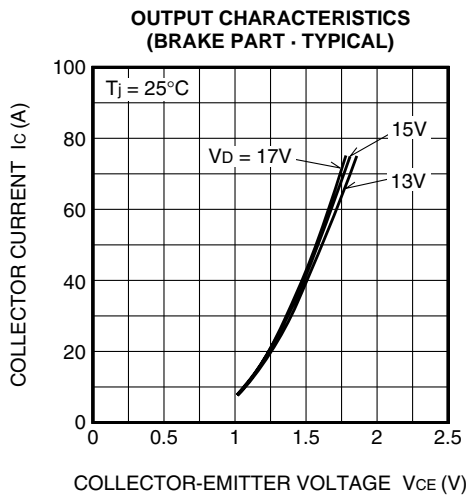
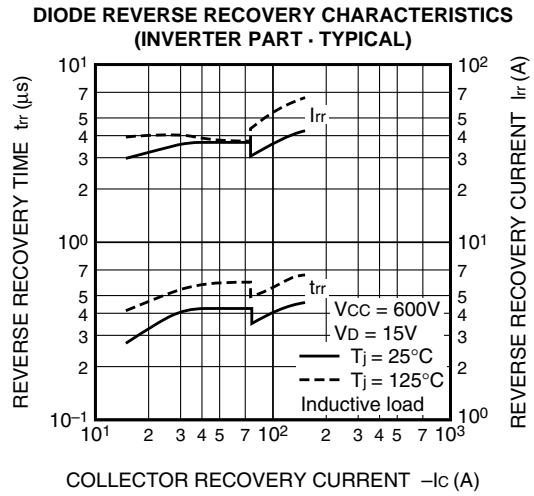
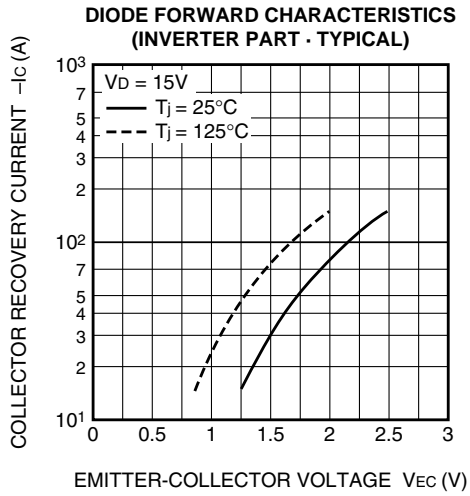


**SWITCHING LOSS CHARACTERISTICS
(TYPICAL)**



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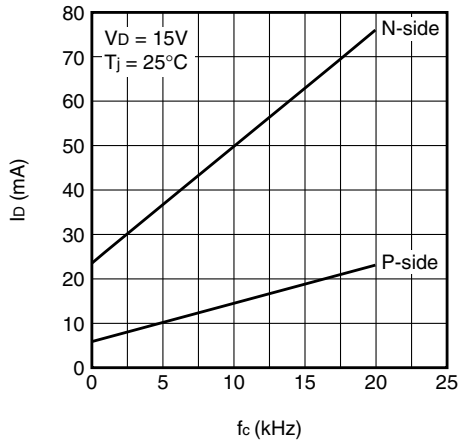
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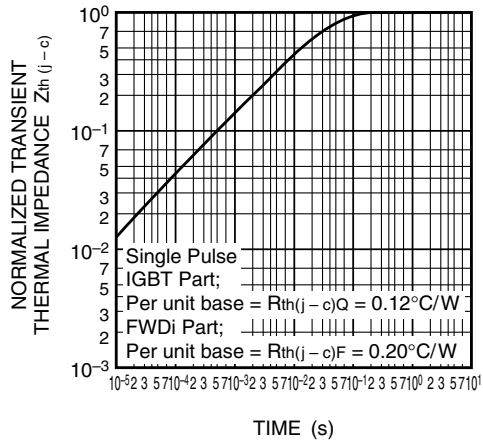
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FLAT-BASE TYPE
INSULATED PACKAGE

**Id VS. fc CHARACTERISTICS
(TYPICAL)**



**TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(INVERTER PART)**



**TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(BRAKE PART)**

